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# 2SD669, 2SD669A

Silicon NPN Epitaxial

# HITACHI

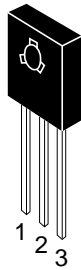
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## Application

Low frequency power amplifier complementary pair with 2SB649/A

## Outline

TO-126 MOD



1. Emitter
2. Collector
3. Base

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## 2SD669, 2SD669A

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### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Item	Symbol	Ratings		Unit
		2SD669	2SD669A	
Collector to base voltage	V <sub>CBO</sub>	180	180	V
Collector to emitter voltage	V <sub>CEO</sub>	120	160	V
Emitter to base voltage	V <sub>EBO</sub>	5	5	V
Collector current	I <sub>C</sub>	1.5	1.5	A
Collector peak current	I <sub>C(peak)</sub>	3	3	A
Collector power dissipation	P <sub>C</sub>	1	1	W
	P <sub>C</sub> <sup>*1</sup>	20	20	W
Junction temperature	T <sub>J</sub>	150	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	-55 to +150	°C

Note: 1. Value at T<sub>c</sub> = 25°C.

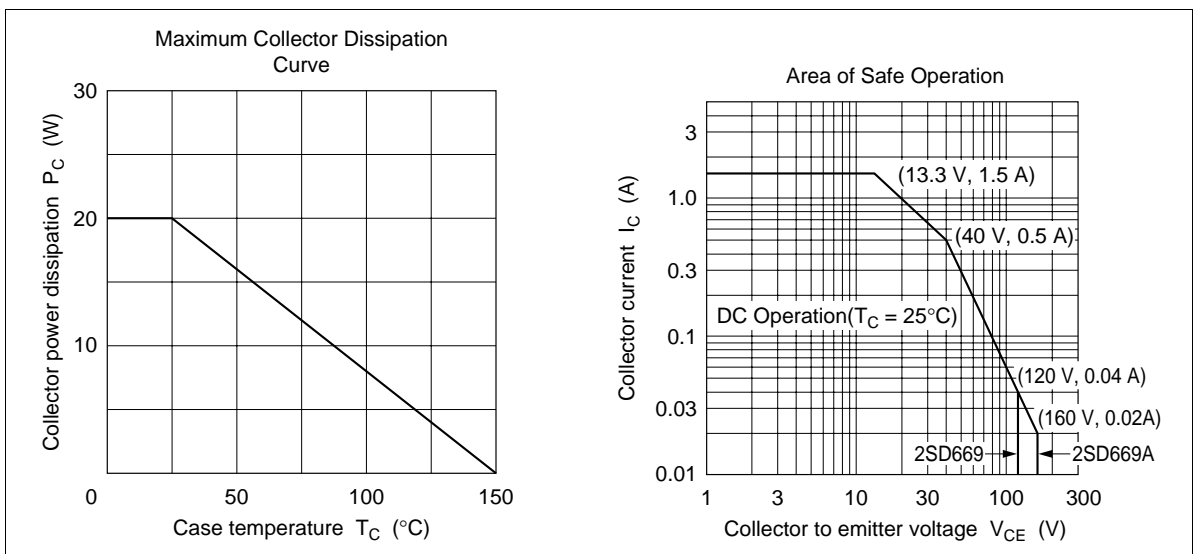
Electrical Characteristics (Ta = 25°C)

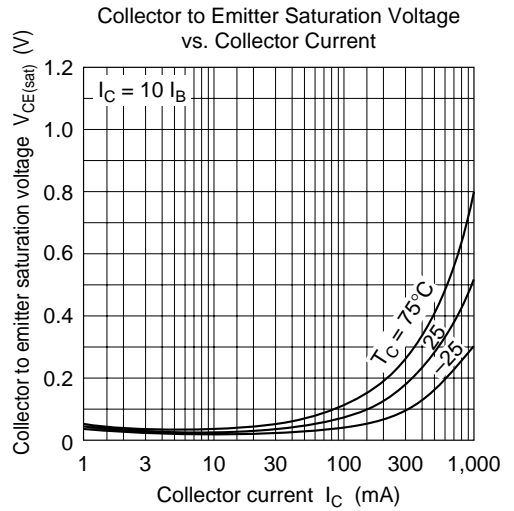
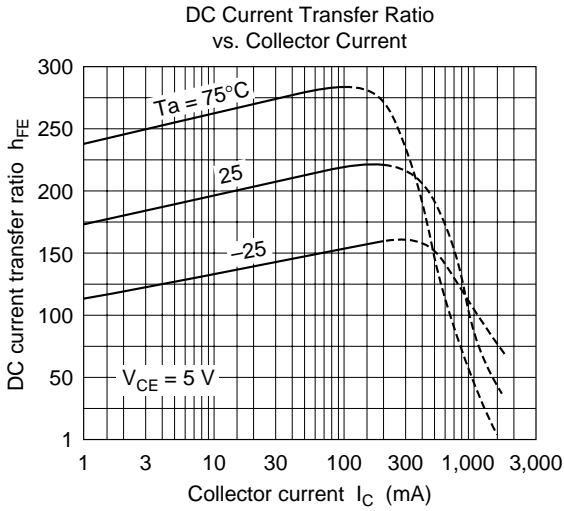
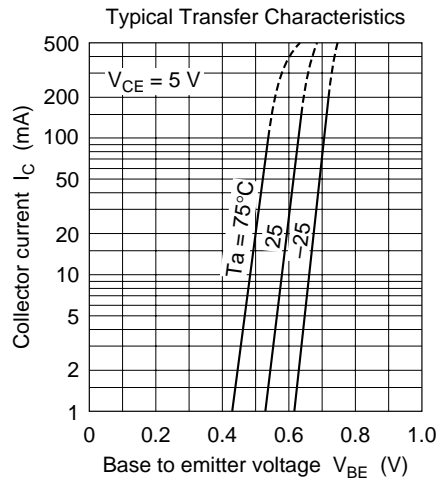
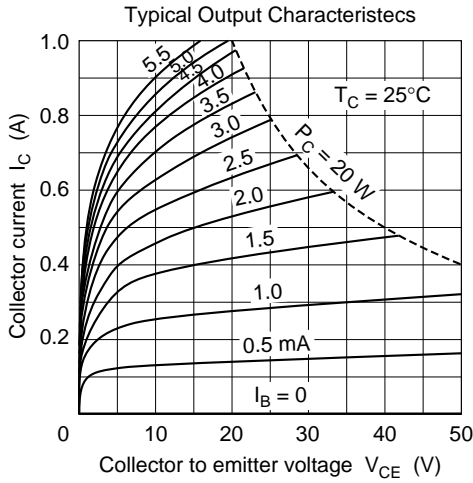
Item	Symbol	2SD669			2SD669A			Unit	Test conditions
		Min	Typ	Max	Min	Typ	Max		
Collector to base breakdown voltage	$V_{(BR)CBO}$	180	—	—	180	—	—	V	$I_C = 1 \text{ mA}, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	120	—	—	160	—	—	V	$I_C = 10 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	5	—	—	V	$I_E = 1 \text{ mA}, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	10	—	—	10	$\mu\text{A}$	$V_{CB} = 160 \text{ V}, I_E = 0$
DC current transfer ratio	$h_{FE1}^{*1}$	60	—	320	60	—	200		$V_{CE} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
	$h_{FE2}$	30	—	—	30	—	—		$V_{CE} = 5 \text{ V}, I_C = 500 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1	—	—	1	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}^{*2}$
Base to emitter voltage	$V_{BE}$	—	—	1.5	—	—	1.5	V	$V_{CE} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Gain bandwidth product	$f_T$	—	140	—	—	140	—	MHz	$V_{CE} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Collector output capacitance	$C_{ob}$	—	14	—	—	14	—	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$

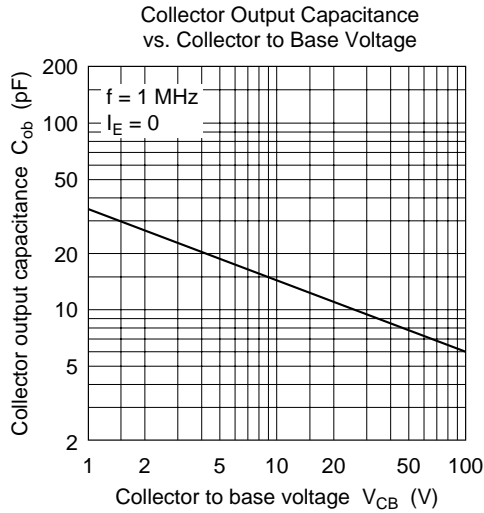
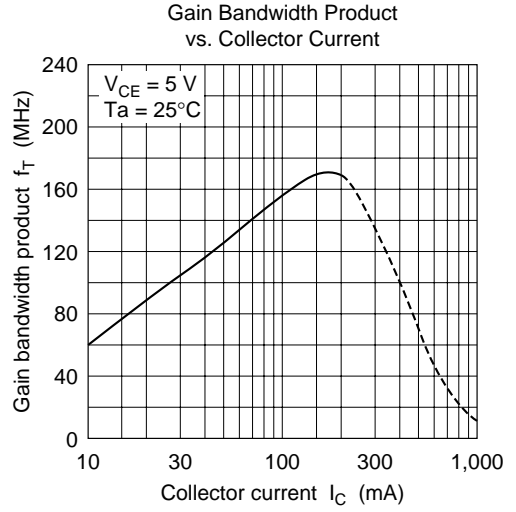
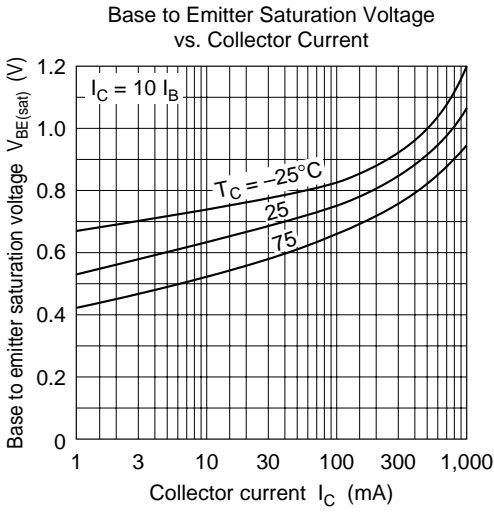
Notes: 1. The 2SD669 and 2SD669A are grouped by  $h_{FE1}$  as follows.

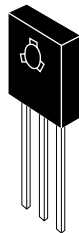
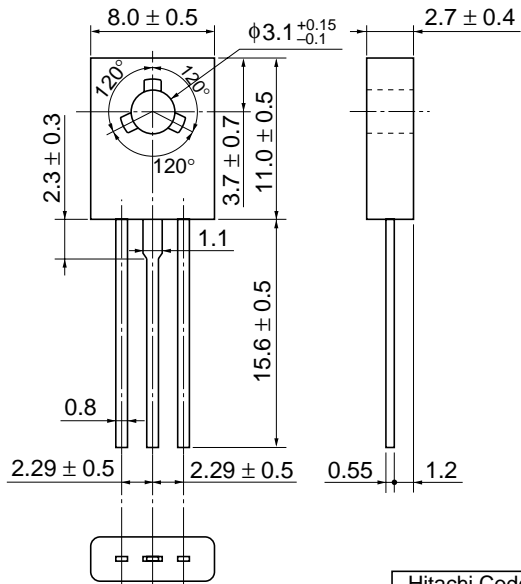
2. Pulse test.

	B	C	D
2SD669	60 to 120	100 to 200	160 to 320
2SD669A	60 to 120	100 to 200	—









Hitachi Code	TO-126 Mod
JEDEC	—
EIAJ	—
Weight (reference value)	0.67 g

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